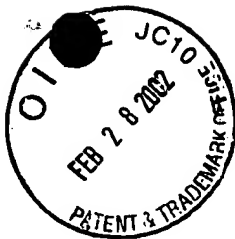


1201.63407



PATENT APPLICATION

#11/B/Ext
Time
3-19-02
Z. Gales

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re U.S. Patent Application)

Applicant: Nayfeh et al.)

Serial No.: 09/496,506 ✓)

Filed: February 2, 2000)

For: SILICON NANOPARTICLE)
FIELD EFFECT TRANSISTOR)
AND TRANSISTOR MEMORY)
DEVICE)

Art Unit: 1741)

Examiner: Crane, S.)

I hereby certify that this paper is being deposited with
the United States Postal Service as FIRST-CLASS mail
in an envelope addressed to: Assistant Commissioner
for Patents, Washington, D.C. 20231, on this date.

2/19/02
Date F-CLASS.WCM
Appr. February 20, 1998
Registration No. 38132
Attorney for Applicant

RECEIVED
MAR - 8 2002
TC 1700

AMENDMENT A

Assistant Commissioner for Patents
Washington, D.C. 20231

Dear Sir:

In response to the office action mailed October 4, 2001, please amend the
application as follows:

In the Claims:

Please cancel claim 3 and amend claims 1, 5, 6, 7 and 8 as follows:

RECEIVED
MAR 14 2002
TC 2800 MAIL ROOM